Supplementary information

Improving the interfacial properties of CZTS photocathode by Ag substitution.

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	Cu	Ag	Zn	Sn	S	Ag/(Cu+Ag) (%)
CZTS	2.60	0	1.56	1	5.80	0
8% Ag	1.53	0.15	1.19	1	6.04	9.38
10% Ag	1.68	0.22	1.08	1	5.45	11.58

Table 1: Atomic ratios of ACZTS films determined by SEM-EDX by taking the average of 5 points.

	4% Ag	8%Ag
0° - 30°	13.87%	22.15%
30° - 50°	18.25%	25.33%
50° - 70°	21.59%	32.63%

Table 2: Ag/(Cu+Ag) ratios determined by angle resolved XPS for 4%Ag and 8%Ag absorbers for 3 different take-off angle channels.



Figure S 1: X-ray diffraction spectra for CZTS and highest substituted 10%Ag thin films.



Figure S 2: Current density (J) – vs potential curves (V) of CZTS/CdS(x)/Pt in $1M K_2HPO_4/KH_2PO_4$ solution (pH 7) under chopped solar -simulated AM 1.5G light illumination. X represents CdS chemical bath deposition time. 14min is determined to be the optimized CdS thickness for PEC setup.



Figure S 3: HC-STH efficiency curve for $(Cu_{1-x}Ag_x)_2ZnSnS_4/CdS/Pt$ photocathodes in 1M K2HPO4/KH2PO4 solution (pH 7) under constant solar-illuminated AM 1.5G light irradiation.

Photocathode stack	Method of Onset Potential Determination			
	Potential at	Potential at	Potential where	Start of
	photocurrent of	photocurrent	photocurrent almost	derivative
	0.05 mA cm ⁻²	of 0.1 mA cm ⁻²	disappears	curve
CZTS (this work)	0.7 V _{RHE}	0.55 V _{RHE}	> 0.7 V _{RHE}	0.65 V _{RHE}
8%Ag (this work)	0.88 V_{RHE} (excluding photocurrent transients) > 0.95 V_{RHE} including photocurrent transients	0.72 V _{RHE}	> 0.9 V _{RHE}	0.85 V _{RHE}
[1] ZnSe CIGSe/CdS/Ti/Mo/Pt				
[²] CIGSe/CdS/Pt	0.05 VKHE		0.75 Vpus	
[³] CIGZS/CdS/TiO ₂ /Pt				

[⁴] ACGSe/CdS/Pt	0.7 V _{RHE}		
[⁵] CZTS/CdS/TiO ₂ /Pt	0.86 V _{RHE}		
[⁶] CZTGS/CdS/In ₂ S ₃ /Pt	0.6 V _{RHE}		
[⁷] CBTSSe/CdS/TiO ₂ /Pt	0.56 V _{RHE}		
[⁸] p-InP/TiO ₂ /Pt	0.8 V _{RHE}		
[⁹] CIGS/CdS/Pt	0.89 V _{RHE}		
[¹⁰] Cu ₂ O/AZO/TiO ₂ /Pt		0.7 V _{RHE}	
[¹¹] Cu ₂ O/NiMo		0.53 V _{RHE}	

Table 3: Selected photocathodes reported in literature with the different photocathode stacks, method of determining onset potential and reported onset potentials. Papers reporting onset potential without definition of how it is derived is not being listed here.



Figure S 4: Current density-potential curves of ACZTS/CdS photocathodes in Na₂SO₄ (pH 9.5) solution under chopped solarsimulated AM1.5G light irradiation before platinum catalyst deposition.



Figure S 5: (a) Time course curve for H_2 and O_2 evolution over 8%Ag/CdS/Pt in 1M K₂HPO₄/KH₂PO₄ solution (pH 7) under simulated sunlight (AM 1.5G) at 0 V_{RHE} applied potential. Solid line represents time course curve for one-half of the electrons passing for H_2 and one-quarter of the electrons for O_2 . (b) Corresponding current-time curve for the Faradaic efficiency measurement.



Figure S 6: PV EQE of ACZTS/CdS/ITO photovoltaic (PV) cells with CdS optimized for PEC.



Figure S 7: Drift-diffusion simulations of CZTS/CdS with bulk and interface defects and a combination of both.

	CZTS	CdS	
Bandgap (eV)	1.5	2.4	
Electron affinity (eV)	4.0	4.2	
Dielectric constant	6.8	10	
Conduction band effective DOS (cm ⁻³)	2.2 x 10 ¹⁸	2.2 x 10 ¹⁸	
Valence band effective DOS (cm ⁻³)	1.8 x 10 ¹⁹	1.8 x 10 ¹⁹	
Electron thermal velocity (cm/s)	107	107	
Hole thermal velocity (cm/s)	107	107	
Electron mobility (cm ² /Vs)	100	100	
Hole mobility (cm²/Vs)	25	25	
Carrier concentration (cm ⁻³)	1015	1017	
	Bulk defect	Interface defect	
Туре	Single acceptor	Acceptor	
Electron capture cross section (cm ²)	10-14	5 x 10 ⁻¹⁴	
Hole capture cross section (cm ²)	10-16	10-14	
Energetic distribution	Gaussian, 0.25 V above VB	Gaussian, 0.6 V above VB	
Total defect density	2.3 x 10 ¹⁵ cm ⁻³	8 x 10 ¹² cm ⁻²	

Table 4: Parameters used for SCAPS simulation in Figure S7.



Figure S 8: PV EQE of ACZTS/CdS/ITO with CdS optimized for PV.



Figure S 9: Nyquist plots of CZTS/CdS/ITO and 8%Ag/CdS/ITO done in PV setup.



Figure S 10: (a) d(EQE)/dE plots of ACZTS/CdS using optimized PV CdS. (b) Corresponding extracted bandgap of ACZTS.



Figure S 11:Valence scans of (a) CZTS, (b) 4%Ag and (c) 8%Ag absorbers.

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